TOSHIBA Intelligent Power Module Silicon N Channel IGBT

## **MIG75Q201H**

# High Power Switching Applications Motor Control Applications

- Integrates inverter, brake power circuits & control circuits (IGBT drive units, protection units for over-current, under-voltage & over-temperature) in one package.
- The electrodes are isolated from case.

• High speed type IGBT :  $V_{CE (sat)} = 3.5 \text{ V (Max)}$ 

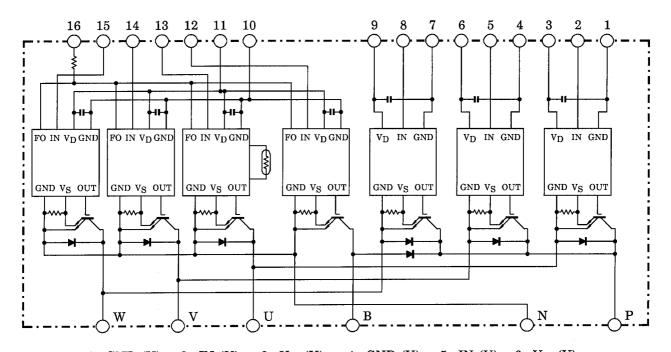
 $t_{off} = 2.5 \mu s (Max)$ 

 $t_{rr} = 0.21 \mu s \text{ (Max)}$ 

• Package dimensions: TOSHIBA 2-136A1A

• Weight:

#### **Equivalent Circuit**



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1. GND (U) 2. IN (U) 3.  $V_D$  (U) 4. 7. GND (W) 8. IN (W) 9.  $V_D$  (W) 10.

4. GND (V) 5. IN (V) 6.  $V_D$  (V) 10.GND (L) 11. $V_D$  (L) 12.IN (B)

13.IN (X) 14.IN (Y) 15.IN (Z) 16.FO

2001-05-29

### Maximum Ratings ( $T_j = 25$ °C)

Stage	Characteristic	Condition	Symbol	Ratings	Unit
Inverter	Supply voltage	P-N power terminal	V <sub>CC</sub>	900	V
	Collector-emitter voltage	_	V <sub>CES</sub>	1200	V
	Collector current	Tc = 25°C, DC	IC	75	Α
ilivertei	Forward current	Tc = 25°C, DC	lF	75	Α
	Collector power dissipation	Tc = 25°C	PC	600	W
	Junction temperature	_	Tj	150	°C
Brake	Supply voltage	P-N power terminal	V <sub>CC</sub>	900	V
	Collector-emitter voltage	_	V <sub>CES</sub>	1200	V
	Collector current	Tc = 25°C, DC	IC	50	Α
	Reverse voltage	_	V <sub>R</sub>	1200	V
	Forward current	Tc = 25°C, DC	lF	50	Α
	Collector power dissipation	Tc = 25°C	PC	400	W
	Junction temperature	_	Tj	150	°C
	Control supply voltage	V <sub>D</sub> -GND terminal	V <sub>D</sub>	20	V
Control	Input voltage	IN-GND terminal	V <sub>IN</sub>	20	V
Control	Fault output voltage	FO-GND (L) terminal	V <sub>FO</sub>	20	V
	Fault output current	FO sink current	I <sub>FO</sub>	14	mA
	Operating temperature	_	TC	-20 ~ +100	°C
Module	Storage temperature range	_	T <sub>stg</sub>	-40 ~ +125	°C
	Isolation voltage	AC 1 minute	V <sub>ISO</sub>	2500	V
	Screw torque	M5	_	3	Nm

## Electrical Characteristics ( $T_j = 25$ °C)

#### a. Inverter Stage

Characteristic	Symbol	Test Condition		Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CEX</sub>	V <sub>CE</sub> = 1200V	T <sub>j</sub> = 25°C	_	_	1	- mA
			T <sub>j</sub> = 125°C	_	_	20	
Collector-emitter saturation voltage	V <sub>CE</sub> (sat)	$V_D = 15 \text{ V}, I_C = 75 \text{ A}$ $V_{IN} = 3 \text{ V} \rightarrow 0 \text{ V}$	T <sub>j</sub> = 25°C	_	2.7	3.5	V
			T <sub>j</sub> = 125°C	_	2.6	_	
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 75A		_	2.0	2.5	V
	t <sub>on</sub>	$V_{CC}$ = 600 V, $I_{C}$ = 75 A $V_{D}$ = 15 V, $V_{IN}$ = 3 V $\leftrightarrow$ 0 V Inductive load		0.8	1.5	2.2	
	t <sub>c (on)</sub>			_	0.3	0.6	
Switching time	t <sub>rr</sub>			_	0.14	0.21	μs
	t <sub>off</sub>		(Note 1)	_	1.5	2.5	
	t <sub>c (off)</sub>			_	0.25	0.5	



#### b. Brake Stage

Characteristic	Symbol	Test Condition		Min	Тур.	Max	Unit
Collector cut-off current	ICEX	V <sub>CE</sub> = 1200V	T <sub>j</sub> = 25°C	-	_	1	- mA
Conector cut-on current			T <sub>j</sub> = 125°C	1	_	20	
Collector-emitter saturation	V <sub>CE (sat)</sub>	$V_D = 15 \text{ V}, I_C = 50 \text{ A}$ $V_{IN} = 3 \text{ V} \rightarrow 0 \text{ V}$	T <sub>j</sub> = 25°C	_	2.7	3.5	V
voltage			T <sub>j</sub> = 125°C	_	2.6	_	
Reverse current	I <sub>R</sub>	VR = 1200 V		1	_	1	- mA
Reverse current				_	_	20	
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 50A		_	2.0	2.7	V
	t <sub>on</sub>			0.8	1.5	2.2	
	t <sub>c (on)</sub>	$V_{CC}$ = 600 V, $I_{C}$ = 50 A $V_{D}$ = 15 V, $V_{IN}$ = 3 V $\leftrightarrow$ 0 V Inductive load		_	0.5	1.0	
Switching time	t <sub>rr</sub>			_	0.30	0.45	μs
	t <sub>off</sub>		(Note 1)	_	1.5	2.5	
	t <sub>c (off)</sub>			_	0.3	0.6	

#### c. Control Stage ( $T_j = 25$ °C)

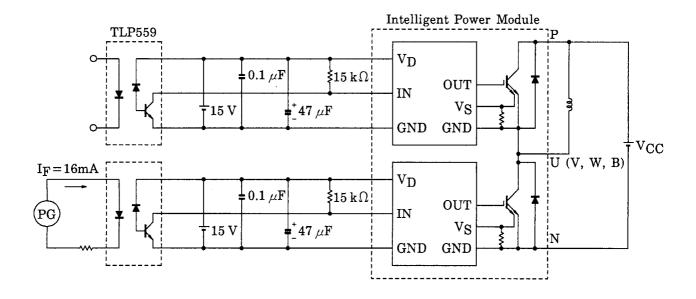
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Control circuit current	High side	I <sub>D (H)</sub>	- V <sub>D</sub> = 15 V	_	20	30	mA
	Low side	I <sub>D (L)</sub>		_	80	120	
Input-on signal voltage		V <sub>IN (on)</sub>	V <sub>D</sub> = 15 V, I <sub>C</sub> = 75 mA	0.9	1.1	1.3	V
Fault output current	Protection	I <sub>FO (on)</sub>		8	10	12	mA
	Normal	I <sub>FO (off)</sub>	_	_	_	1	
Over current protection trip level	Inverter	00	V <sub>D</sub> = 15 V, T <sub>j</sub> = 125°C	105	150	_	А
	Brake	- oc		70	100	_	
Short circuit protection trip level	Inverter	00	V <sub>D</sub> = 15 V, T <sub>j</sub> = 125°C	157	225	-	А
	Brake	SC		105	150	_	
Over current cut-off time		t <sub>off (OC)</sub>	V <sub>D</sub> = 15 V	_	10	-	μs
Over temperature protection	Trip level	OT	Case temperature	111	118	125	°C
	Reset level	OTr		93	100	107	-0
Control supply under voltage protection	Trip level	UV		11.3	12.0	12.7	
	Reset level	UVr	_	11.8	12.5	13.2	V
Fault output pulse width		t <sub>FO</sub>	V <sub>D</sub> = 15 V	1	2	3	ms

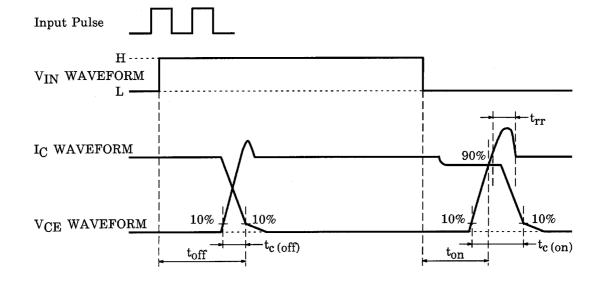


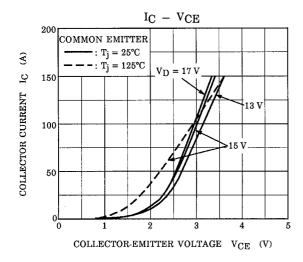
#### d. Thermal Resistance ( $T_j = 25$ °C)

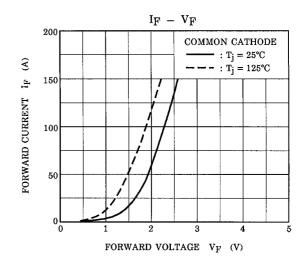
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
		Inverter IGBT	_	_	0.208	°C/W
Junction to case thermal resistance	R <sub>th (j-c)</sub>	Inverter FRD	_	_	0.50	
		Brake IGBT	_	_	0.312	
		Brake FRD	_	_	1.00	
Case to fin thermal resistance	R <sub>th (c-f)</sub>	Compound is applied	_	0.04	ı	°C/W

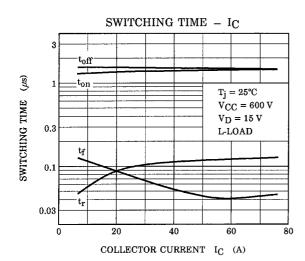
Note 1: Switching time test circuit & timing chart

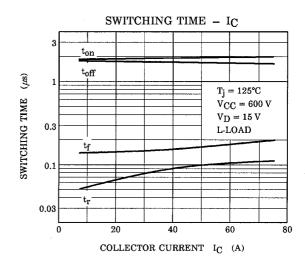


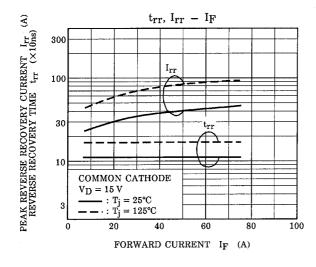


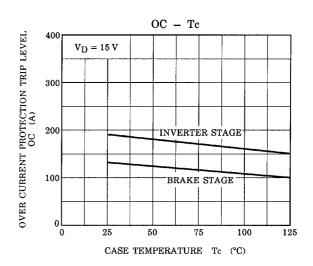


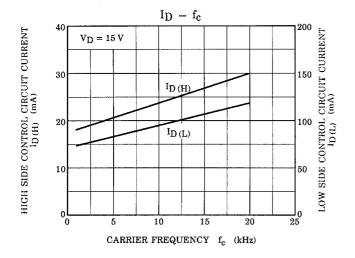


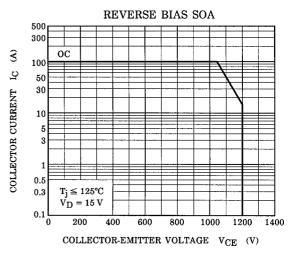


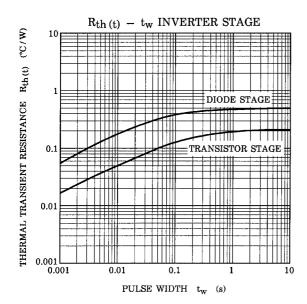


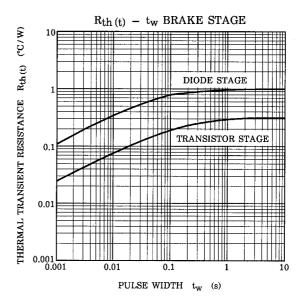






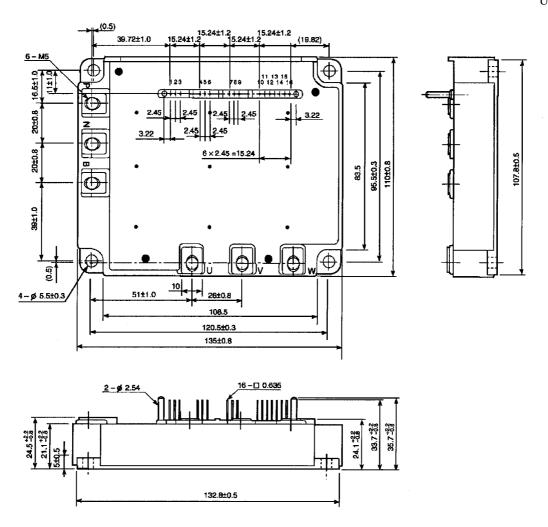






#### Package Dimensions: TOSHIBA 2-136A1A

Unit: mm



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